EAST Search History

EAST Search History (Prior Art)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	99	(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface with germanium and bipolar and collector and emitter and transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 21:58
L3	83	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250")".PN."	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 21:59
L4	83	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250")".PN."	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 21:59
L5	74	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250")".PN."	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; IBM_TDB	OR	ON	2009/12/10 21:59
L6	64	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250")".PN."	US-PGPUB; USPAT	OR	ON	2009/12/10 21:59
L7	7	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250").PN.	US-PGPUB; USPAT	OR	ON	2009/12/10 22:00
L8	18	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:00

L9	9	("20010003667" "20020132438" "20030189239" "3725161" "3725161" "6437376" "6586297" "6437376" "6686250").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; IBM_TDB	OR	ON	2009/12/10 22:00
L10	236	(@ad< "20040310" and willow and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:05
L11	257144	(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate ans semiconductor and heterojunction	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:06
L12	170	(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate and semiconductor and heterojunction	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:06
L13	0	(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate and semiconductor and heterojunction and ge- enriched	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:07
L14	0	(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate and semiconductor and heterojunction and germanium-enriched	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:07

L15		(@ad<"20040310" @rlad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate and semiconductor and heterojunction and enriched	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:07
L16	52	(@ad<"20040310") and silicon near germanium near base and surface and germanium and bipolar and collector and emitter and transistor and substrate and semiconductor and heterojunction and 257/197,198,e29.033, e29.188.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 22:09
S1	5	("20030189239" "3725161" "6437376" "6686250"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 16:52
S2	397	((ge germanium) near (rich enriched concentration) ge-enriched) and bipolar near transistor and collector and emitter and base and (@ad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:23
S3	221	((ge germanium) near (rich enriched concentration) ge- enriched) and heterojunction near bipolar near transistor and collector and emitter and base and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:24
S 4	212	((ge germanium) near (rich enriched concentration) ge-enriched) and heterojunction near bipolar near transistor and collector same emitter same base and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:24
S5	19	((ge germanium) near (rich enriched high near concentration) ge-enriched) and heterojunction near bipolar near transistor and collector same emitter same base and (@ad<"20040310") @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:24

S6	3	((ge germanium) near (rich enriched high near concentration) ge-enriched) with base and heterojunction near bipolar near transistor and collector and emitter and base and (@ad< "20040310" @rlad< "20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:46
S7	19	((ge germanium) near (rich enriched high near concentration) ge-enriched) with base and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 18:56
S8	151	((ge germanium) near (rich enriched high near concentration) ge-enriched) with sige and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 19:10
S9	30	((ge germanium) near (rich enriched high near concentration) ge-enriched) with (silicon near germanium sige) and collector and emitter and base and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 19:10
S10	15	((ge germanium) near (rich enriched high near concentration) ge-enriched) with (silicon near germanium sige) and collector and emitter and base and hbt and (@ad<"20040310"	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 19:10
S11	2	"0490111"	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 19:16
S12	0	"ep0490111"	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 19:16
S13	16	pong-fei near lu	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 19:16
S14	21	"435135"	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 19:22

S15	2	"5089428".pn.	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 19:24
S16	22	"881669"	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 20:36
S17	2	"6624017".pn.	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 20:38
S18	4	"2005088721".pn.	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	ON	2008/10/31 20:43
S19	14	ge-enriched	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:03
S20	226	ge-rich	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:05
S21	92	ge-rich with sige	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:05
S22	80	ge-rich with sige and transistor	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:05
S23	1	ge-rich with sige with base with emitter and transistor	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:05
S24	0	ge-rich with sige with base with emitter and transistor and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:10
S25	0	ge-rich same sige same base same emitter and transistor and (@ad< "20040310" @rlad< "20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:11
S26	2	ge near rich same sige same base same emitter and transistor and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:11
S27	9	ge near (rich concentration high) with surface same sige same base same emitter and transistor and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:15
S28	136	ge same sige same oxidized and (@ad< "20040310" @rlad< "20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:20
S29	42	ge near (concentration rich enriched high) same sige same oxidized and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:20

S30	7	ge near (concentration rich enriched high) same sige same oxidized and (@ad<"20040310" @rlad<"20040310") and hbt	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 21:21
S31	4	ge near (concentration rich enriched high) same sige same oxidized and (@ad<"20040310" @rlad<"20040310") and hbt and emitter and collector and base	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 22:00
S32	0	"6651697".pn. and S27	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 22:12
S33	1	"6651697".pn. and "13"	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 22:12
S34	1	"6780725".pn. and "13"	US-PGPUB; USPAT; USOCR	OR	ON	2008/10/31 22:13
S35	0	h09288115	US-PGPUB; USPAT; USOCR; JPO; DERWENT	OR	OFF	2008/11/04 09:13
S 36	2	"09288115"	US-PGPUB; USPAT; USOCR; JPO; DERWENT	OR	OFF	2008/11/04 09:13
S37	1	("6437376").PN. and "12"	US-PGPUB; USPAT; USOOR	OR	ON	2008/11/07 11:36
S 38	1	("6437376").PN. and (germanium ge)	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 13:07
S3 9	1	"3725161".pn. and (germanium ge)	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 13:13
S40	6	(US-20040031979-\$ or US-20040123882-\$ or US-20030189239-\$ or US-20020031893-\$).did. or (US-5106767-\$ or US-6780725-\$). did.	US-PGPUB; USPAT	OR	OFF	2008/11/07 14:38
S41	0	S40 and strain	USPAT	OR	OFF	2008/11/07 14:38
S42	0	S40 and strain\$4	USPAT	OR	OFF	2008/11/0 7 14:38
S43	0	"6437376".pn. and ev	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:16
S44	1	S40 and valence	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:16
S45	1	"6437376".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:18
S46	1	"6437376".pn. and emitter	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:19

S47	0	"6437376".pn. and emitter and band and gap and valence	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:22
S48	1	"6437376".pn. and emitter and band and gap	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:22
S49	20	valence near band with ev and hbt and sige	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:27
S50	17	valence near band with ev and hbt and sige and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:27
S51	41	band near gap with ev and hbt and sige and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:33
S52	1	"6437376".pn. and defect	US-PGPUB; USPAT; USOCR	OR	ON	2008/11/07 15:37
S5 3	3	S40 and uniform	US-PGPUB; USPAT	OR	OFF	2008/11/07 15:58
S54	0	"3725161".pn. and surface	US-PGPUB; USPAT	OR	OFF	2008/11/07 16:14
S55	0	"3725161".pn. and (germanium ge)	US-PGPUB; USPAT	OR	OFF	2008/11/07 16:16
S56	0	"3725161".pn. and ge	US-PGPUB; USPAT	OR	OFF	2008/11/07 16:16
S57	1	"3725161".pn.	US-PGPUB; USPAT	OR	OFF	2008/11/07 16:17
S 58	2	"3725161".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/07 16:17
S59	1	"3725161".pn. and (germanium ge)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/07 16:17
S60	1	"6437376".pn. and substrate	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/07 16:35
S61	1	"20020132438".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/05/19 16:11
S62	1	"6617220".pn.	US-PGPUB; USPAT; USOCR	OR	ON	2009/05/19 16:12
S63	27	("4319932" "4338138" "4682409" "4799099" "4839305" "4927774" "4960726" "5008207" "5017990" "5101256" "5117271" "5162245" "5175607" "5194926" "5213989" "5298786" "5488002" "5523245" "5525818" "5557131" "5773350" "5925923" "6020246" "6265276" "6365451" "6465317" "6534372").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 17:31

S64	9	S63 and (germanium sige)	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 17:39
S65	1556	graded with (germanium sige)	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:05
S66	33	graded with (germanium sige) with base and (bjt bipolar near junction near transistor) and (@ad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:06
S67	5	("20030189239" "3725161" "3725161" "6437376" "6437376" "6686250").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:15
S68	18	(rich enriched high near concentration) with (germanium sige) with base and (bjt bipolar near junction near transistor) and (@ad<"20040310"	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:43
S69	5030831	(rich enriched high near concentration) with (germanium sige) (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:54
S70	928	(rich enriched high near concentration) with (germanium sige) and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:54
S71	508	(rich enriched) with (germanium sige) and (@ad<"20040310" @rlad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:55
S72	0	(rich enriched) with (germanium sige) with base with emitter and (@ad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:55
S73	21	concentration with profile with (germanium sige) with base with emitter and (@ad<"20040310")	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 19:55
S74	1	"6362065".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 21:40
S75	1	"5962880".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 21:41
S76	0	"5962880".pn. and ev	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 21:41
S77	1	"5962880".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 21:54

S78	1	"20020132438".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 21:57
S79	1	"6781214" pn. and "120"	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:04
S80	1	"20010003667".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:08
S81	1	"20020132438".pn.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:18
S82	1	"6781214".pn. and "107"	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:24
S83	5	germanium same injection near2 interstitials	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:44
S84	0	germanium same injection near2 interstitials same (oxide oxidation)	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/19 22:46
S85	5	("20030189239" "3725161" "6437376" "6686250") PN.	US-PGPUB; USPAT; USOCR	OR	ON	2009/12/10 19:00
S8 6	63	(@ad<"20040310" @rlad<"20040310") and emitter near contact with germanium	US-PGPUB; USPAT; USOCR	OR	ON	2009/12/10 19:11
S87	4919	(@ad<"20040310" @rlad<"20040310") and emitter near contact enriched near germanium	US-PGPUB; USPAT; USOCR	OR	ON	2009/12/10 19:21
S88	1	(@ad<"20040310" @rlad<"20040310") and emitter near contact and enriched near germanium	US-PGPUB; USPAT; USOCR	OR	ON	2009/12/10 19:21
S8 9	2	(@ad<"20040310" @rlad<"20040310") and emitter and contact and enriched near germanium and silicon near germanium and collector and bipolar and transistor	US-PGPUB; USPAT; USOCR	OR	ON	2009/12/10 19:28
S90	2	(@ad<"20040310" @rlad<"20040310") and emitter and contact and enriched near germanium and silicon near germanium and collector and bipolar and transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 19:28
S91	4	(@ad<"20040310" @rlad<"20040310") and "3725161".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/10 19:31

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